

Title (en)

METHOD FOR FORMING MICROWIRES AND/OR NANOWIRES

Title (de)

VERFAHREN ZUR BILDUNG VON MIKRODRÄHTEN UND/ODER NANODRÄHTEN

Title (fr)

PROCEDE DE REALISATION DE MICROFILS ET/OU DE NANOFILS

Publication

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Application

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Priority

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Abstract (en)

[origin: WO2008074862A1] The invention relates to a method for forming a wire (112) in a layer (102) based on an amorphous or monocrystalline material, comprising the following steps in which: two trenches (110) are formed in the layer so as to extend through one face (101) thereof, said trenches being separated from one another by a portion of the layer and formed by etching the layer on which an etching mask (108) has been disposed; and the layer is annealed in a hydrogenated atmosphere, the etching mask being retained on the layer during said annealing step. The depths and widths of the sections of the two trenches and the width of a section of the above-mentioned portion of the layer are such that the annealing process removes part of said portion of the layer, so that the two trenches then form a single trench (114) in which a remaining part of said portion forms the wire.

IPC 8 full level

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